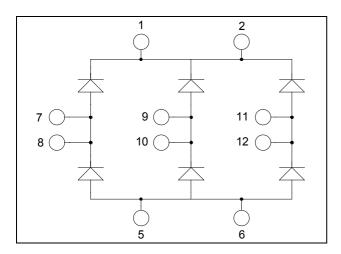


3 Phase rectifier bridge Power Module





Application

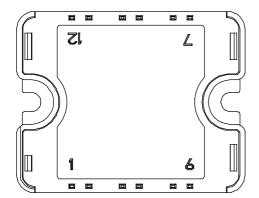
- Input rectifiers for inverter
- Battery DC power supply

Features

- High blocking voltage
- High surge current
- Low leakage current
- Very low stray inductance
 - Symmetrical design
- High level of integration



- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low profile
- RoHS compliant



All multiple inputs and outputs must be shorted together 1/2; 5/6; 7/8; 9/10; 11/12

Absolute maximum ratings

Symbol	Parameter			Max ratings	Unit	
V_R	Maximum DC reverse Voltage			1600	V	
V_{RRM}	Maximum Peak Repetitive Reverse Voltage			1000	V	
I_F	DC Forward Current		$T_C = 80$ °C	40	٨	
I_{FSM}	Non-Repetitive Forward Surge Current	t=10ms	$T_J = 45^{\circ}C$	400	А	

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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All ratings @ $T_j = 25$ °C unless otherwise specified

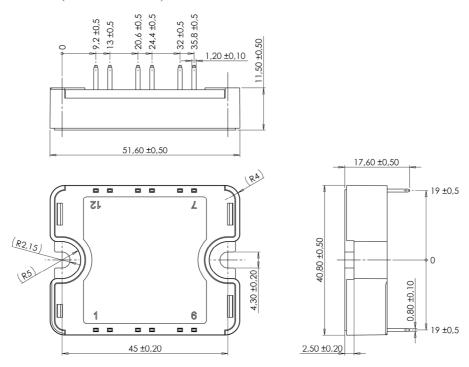
Electrical Characteristics

Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
I_R	Reverse Current	$V_{R} = 1600V$	$T_j = 25$ °C		20		μΑ
			$T_j = 125$ °C		2		mA
$V_{\rm F}$	Forward Voltage	$I_F = 40A$	$T_j = 25$ °C		1.3		17
			$T_j = 125$ °C		1.1		v
V_{T}	On – state Voltage				0.8		V
r_{T}	On – state Slope resistance				10.5		$m\Omega$

Thermal and package characteristics

Symbol	Characteristic			Min	Typ	Max	Unit
R_{thJC}	Junction to Case Thermal Resistance					1.5	°C/W
V_{ISOL}	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
T_{J}	Operating junction temperature range			-40		150	
T _{STG}	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To heatsink	M4	2		3	N.m
Wt	Package Weight					80	g

SP1 Package outline (dimensions in mm)

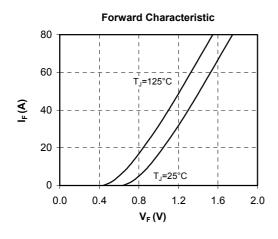


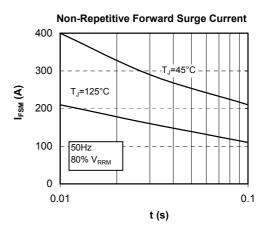
See application note 1904 - Mounting Instructions for SP1 Power Modules on www.microsemi.com

2 - 4

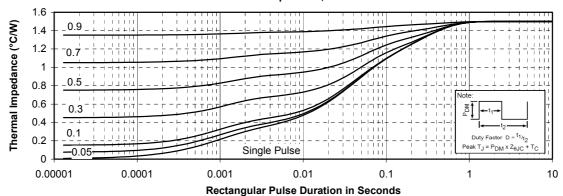


Typical Performance Curve





maximum Effective Transient Thermal Impedance, Junction to Case vs Pulse Duration





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